# NSN 5961-00-252-4299

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.520 inches

#### **Overall Diameter:**

1.250 inches

#### Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### Features Provided:

Hermetically sealed case

Thread Size:

0.190 inches

#### Semiconductor Material:

Germanium

## Voltage Rating In Volts Per Characteristic:

75.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, emitter-to-base, collector open and 60.0

breakdown voltage, collector-to-emitter, base open

#### **Current Rating Per Characteristic:**

60.00 amperes source cutoff current and 10.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

2.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

2 threaded stud and 1 pin

#### **Specification Data:**

80131-release5584 professional/industrial association specification

### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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